NSN 5961-00-057-0314

Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-057-0314 **Inclosure Material:** Glass **Overall Length:** 0.200 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.090 inches Joint Electronic Device Engineering Council/jedec/case Outline Designation: Do-35 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 75.0 reverse voltage, instantaneous **Current Rating Per Characteristic:** 150.00 milliamperes average forward current averaged over a full 60-hz cycle **Power Rating Per Characteristic:** 500.0 milliwatts total power dissipation **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Terminal Type And Quantity:** 2 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: A110a0